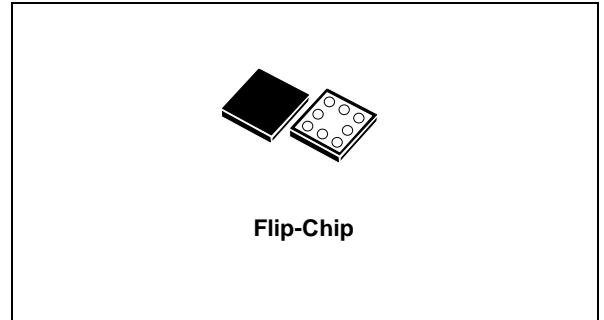


DUAL ULTRA LOW DROP-LOW NOISE BICMOS VOLTAGE REG. FOR USE WITH VERY LOW ESR OUT. CAPACITORS

- INPUT VOLTAGE FROM 2.5V TO 6V
- STABLE WITH LOW ESR CERAMIC CAPACITORS
- ULTRA LOW DROPOUT VOLTAGE (60mV TYP. AT 150mA LOAD, 0.4mV TYP. AT 1mA LOAD)
- VERY LOW QUIESCENT CURRENT (155 μ A TYP. AT NO LOAD, 290 μ A TYP. AT 150mA LOAD; MAX 2 μ A IN OFF MODE)
- GUARANTEED OUTPUT CURRENT UP TO 150mA FOR BOTH OUTPUTS
- DUAL OUTPUT VOLTAGES
- FAST TURN-ON TIME: TYP. 120 μ s ($C_{O}=1\mu$ F, $C_{BYP}=10$ nF AND $I_{O}=1$ mA)
- LOGIC-CONTROLLED ELECTRONIC SHUTDOWN
- INTERNAL CURRENT AND THERMAL LIMIT
- OUTPUT LOW NOISE VOLTAGE 30 μ V_{RMS} OVER 10Hz to 100KHz
- S.V.R. OF 50dB AT 1KHz, 40dB AT 10KHz
- TEMPERATURE RANGE: -40°C TO 125°C



make it suitable for low power applications and in battery powered systems. Regulator ground current increases only slightly in dropout, further prolonging the battery life. Power supply rejection is 50 dB at 1KHz and 40 dB at 10KHz. High power supply rejection is maintained down to low input voltage levels common to battery operated circuits. Shutdown Logic Control function is available for each output, this means that when the device is used as local regulator, it is possible to put a part of the board in standby, decreasing the total power consumption. The LD3986 is designed to work with low ESR ceramic capacitors. Typical applications are in mobile phone and similar battery powered wireless systems.

DESCRIPTION

The LD3986 provides up to 150mA at each output, from 2.5V to 6V input voltage. The ultra low drop-voltage, low quiescent current and low noise

Figure 1: Schematic Diagram

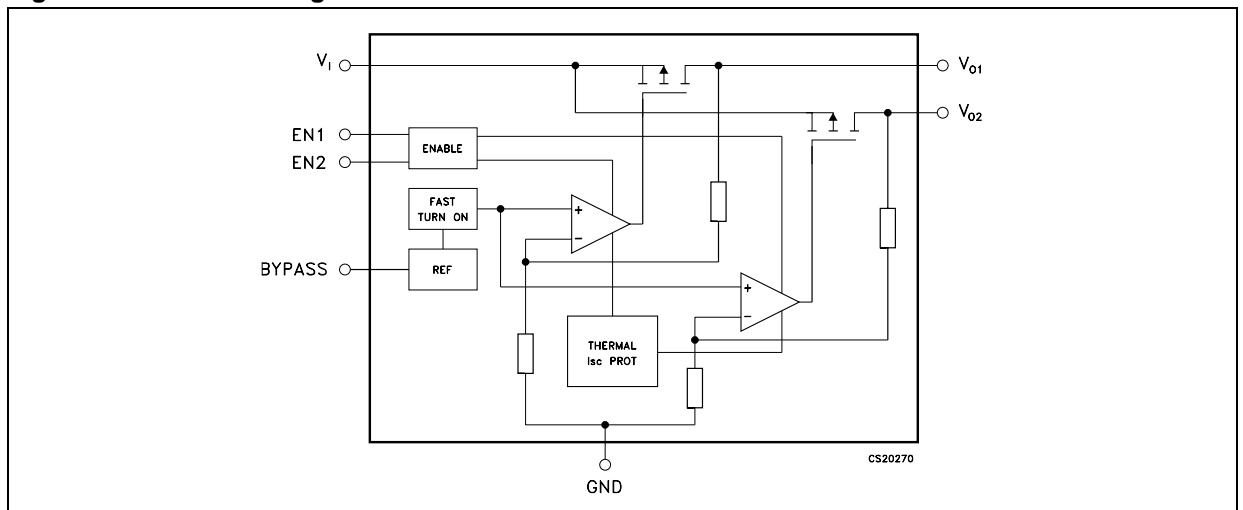


Table 1: Order Codes

Flip-Chip	Flip-Chip (Lead Free)	1 OUTPUT VOLTAGES	2 OUTPUT VOLTAGES
	LD3986J122R-E	1.22 V	1.22 V
LD3986J12248R	LD3986J12248R-E	1.22 V	4.8 V
	LD3986J1828R-E	1.8 V	2.8 V
	LD3986J2528R-E (*)	2.5 V	2.8 V
	LD3986J28R-E	2.8 V	2.8 V
LD3986J285R	LD3986J285R-E	2.85 V	2.85 V
	LD3986J29R-E (*)	2.9 V	2.9 V
	LD3986J30R-E (*)	3.0 V	3.0 V
	LD3986J2830R-E (*)	2.8 V	3.0 V
	LD3986J3133R-E (*)	3.1 V	3.3 V
	LD3986J33R-E	3.3 V	3.3 V

(*) Available on Request.

Table 2: Absolute Maximum Ratings

Symbol	Parameter	Value	Unit
V_I	DC Input Voltage	-0.3 to 6	V
$V_{O1,2}$	DC Output Voltage	-0.3 to $V_I+0.3$	V
$V_{EN1,2}$	ENABLE Input Voltage	-0.3 to $V_I+0.3$	V
I_O	Output Current	Internally limited	
P_D	Power Dissipation	Internally limited	
T_{STG}	Storage Temperature Range	-65 to 150	°C
T_{OP}	Operating Junction Temperature Range	-40 to 125	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied.

Table 3: Thermal Data

Symbol	Parameter	Flip-Chip	Unit
$R_{thj-amb}$	Thermal Resistance Junction-Ambient	120	°C/W

Figure 2: Pin Connection (top through view)

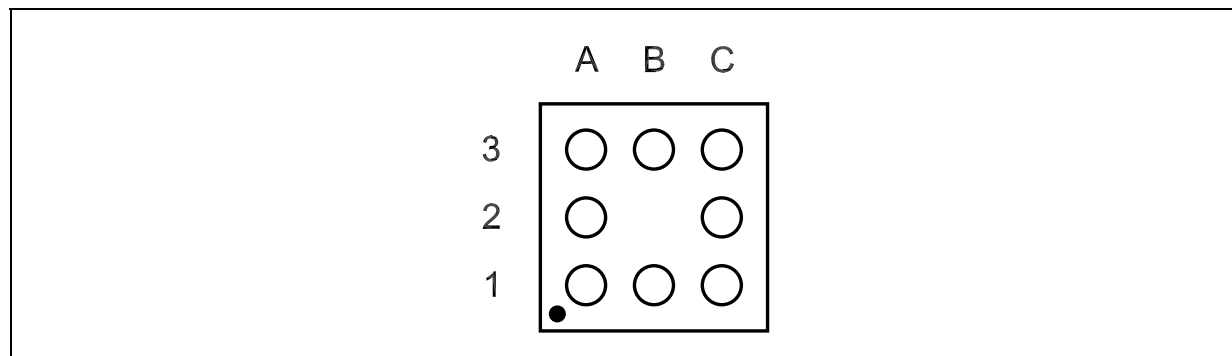


Table 4: Pin Description

Symbol	Pin N°	Name and Function
V_{O2}	A1	Output Voltage 2 of the dual LDO
EN2	B1	Enables voltage for output voltage 2: ON MODE when $V_{EN} \geq 1.4V$, OFF MODE when $V_{EN} \leq 0.4V$ (Do not leave floating, not internally pulled down/up)
BYPASS	C1	Bypass Pin: Connect an external capacitor (usually 10nF) to minimize noise voltage
GND	C2	Common Ground
GND	C3	Common Ground
EN1	B3	Enables voltage for output voltage 1: ON MODE when $V_{EN} \geq 1.4V$, OFF MODE when $V_{EN} \leq 0.4V$ (Do not leave floating, not internally pulled down/up)
V_{O1}	A3	Output Voltage 1 of the dual LDO
V_I	A2	Input Voltage for both LDO

Figure 3: Typical Application Circuit

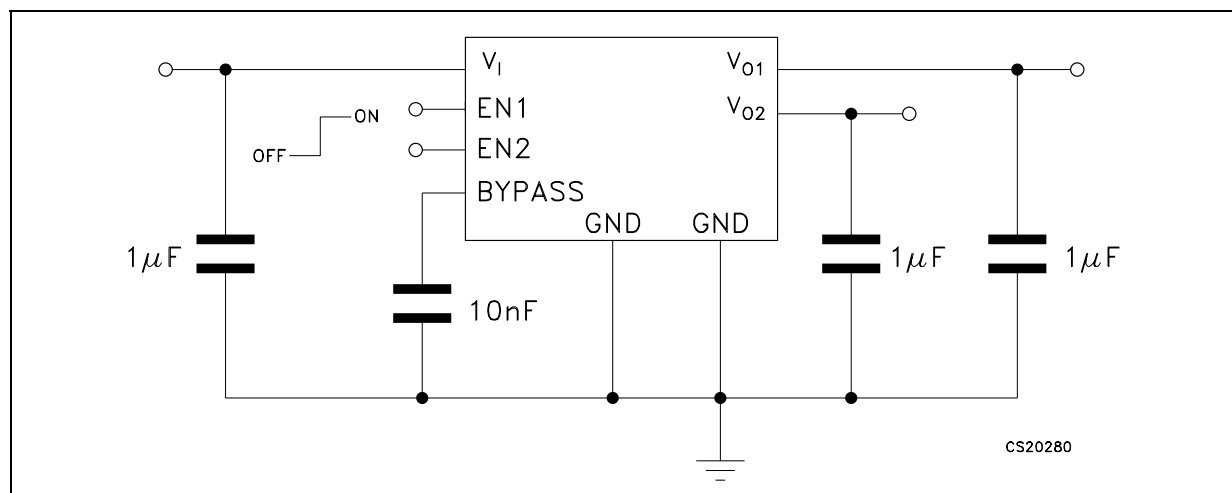


Table 5: Electrical Characteristics For LD3986 ($T_J = 25^\circ\text{C}$, $V_I = V_{O(\text{NOM})} + 0.5\text{V}$, $C_I = C_O = 1\mu\text{F}$, $C_{\text{BYP}} = 10\text{nF}$, $I_O = 1\text{mA}$, $V_{\text{EN}} = 1.4\text{V}$, unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
V_I	Operating Input Voltage		2.5		6	V
ΔV_O	Output Voltage Tolerance	$I_O = 1\text{mA}$	-2.5		2.5	% of V_O
		$T_J = -40$ to 125°C	-3		3	
ΔV_O	Line Regulation (Note 1)	$V_I = V_{O(\text{NOM})} + 0.5\text{V}$ to 6V		0.006	0.092	%/ V
		$T_J = -40$ to 125°C			0.128	
ΔV_O	Load Regulation	$I_O = 1\text{mA}$ to 150mA		0.003	0.006	%/ mA
		$T_J = -40$ to 125°C			0.01	
ΔV_O	Output AC Line Regulation (See fig. 5)	$V_I = V_{O(\text{NOM})} + 1\text{V}$, $I_O = 150\text{mA}$, $t_R = t_F = 30\mu\text{s}$		1.5		mV_{PP}
I_Q	Quiescent Current BOTH ON MODE: $V_{\text{EN}} = 1.4\text{V}$	$I_O = 0$		150		μA
		$I_O = 0$ $T_J = -40$ to 125°C			200	
		$I_O = 0$ to 150mA			290	
		$I_O = 0$ to 150mA $T_J = -40$ to 125°C			370	
	BOTH OFF MODE: $V_{\text{EN}} = 0.4\text{V}$	$T_J = -40$ to 125°C		0.001	2	
		$T_J = -40$ to 125°C			4	
	ONE REGULATOR ON MODE: $V_{\text{EN}} = 1.4\text{V}$	$I_O = 0$			95	
		$I_O = 0$ $T_J = -40$ to 125°C				130
		$I_O = 0$ to 150mA				165
		$I_O = 0$ to 150mA $T_J = -40$ to 125°C				220
V_{DROP}	Dropout Voltage (Note 2)	$I_O = 1\text{mA}$		0.4		mV
		$I_O = 1\text{mA}$ $T_J = -40$ to 125°C			2	
		$I_O = 150\text{mA}$			50	
		$I_O = 150\text{mA}$ $T_J = -40$ to 125°C			100	
SVR	Supply Voltage Rejection (See fig. 4)	$V_I = V_{O(\text{NOM})} + 0.25\text{V} \pm$ $V_{\text{RIPPLE}} = 0.1\text{V}$, $I_O = 50\text{mA}$ $V_{O(\text{NOM})} < 2.5\text{V}$, $V_I = 2.55\text{V}$	$f = 1\text{KHz}$	50		dB
			$f = 10\text{KHz}$	40		
I_{SC}	Short Circuit Current	$R_L = 0$		600		mA
$I_{O(\text{PK})}$	Peak Output Current	$V_O \geq V_{O(\text{NOM})} - 5\%$	300	550		mA
V_{EN}	Enable Input Logic Low (Note 3)	$V_I = 2.5\text{V}$ to 6V $T_J = -40$ to 125°C			0.4	V
	Enable Input Logic High (Note 3)		1.4			
I_{EN}	Enable Input Current	$V_{\text{EN}} = 0.4\text{V}$ $V_I = 6\text{V}$		± 10		nA
X_{TALK}	Crosstalk Rejection	$\Delta I_{\text{LOAD}1} = 150\text{mA}$ at 1KHz rate $I_{\text{LOAD}2} = 1\text{mA}$, V_{O2} under test		40		μV
		$\Delta I_{\text{LOAD}2} = 150\text{mA}$ at 1KHz rate $I_{\text{LOAD}1} = 1\text{mA}$, V_{O1} under test		40		
eN	Output Noise Voltage	$B_W = 10\text{Hz}$ to 100KHz $C_O = 1\mu\text{F}$		30		μV_{RMS}
t_{ON}	Turn On Time (Note 4)	$C_{\text{BYP}} = 10\text{nF}$		50		μs
T_{SHDN}	Thermal Shutdown (Note 4)	(Note 3)		160		$^\circ\text{C}$

TYPICAL PERFORMANCE CHARACTERISTICS ($T_j = 25^\circ\text{C}$, $V_I = V_{O(\text{NOM})} + 0.5\text{V}$, $C_I = C_O = 1\mu\text{F}$, $C_{\text{BYP}} = 10\text{nF}$, $I_O = 1\text{mA}$, $V_{\text{EN}} = 1.4\text{V}$, unless otherwise specified)

Figure 6: $V_{O1,2}$ vs Temperature

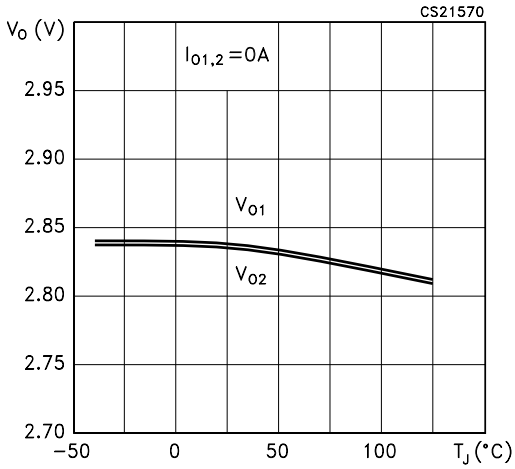


Figure 7: $V_{O1,2}$ vs Temperature

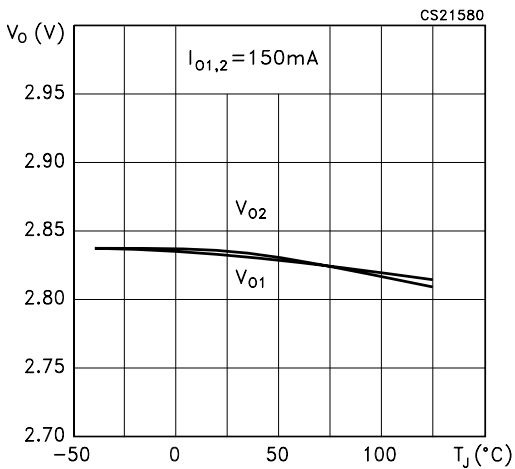


Figure 8: Line Regulation vs Temperature

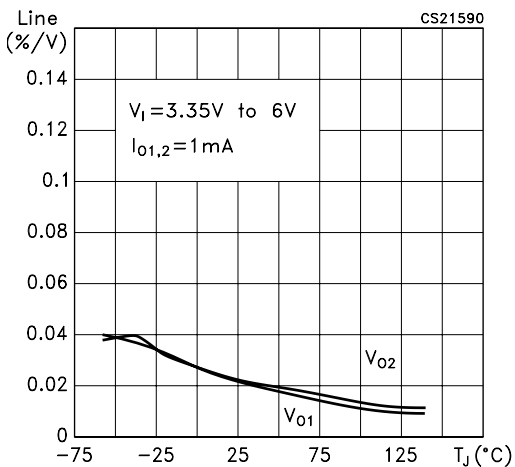


Figure 9: Load Regulation vs Temperature

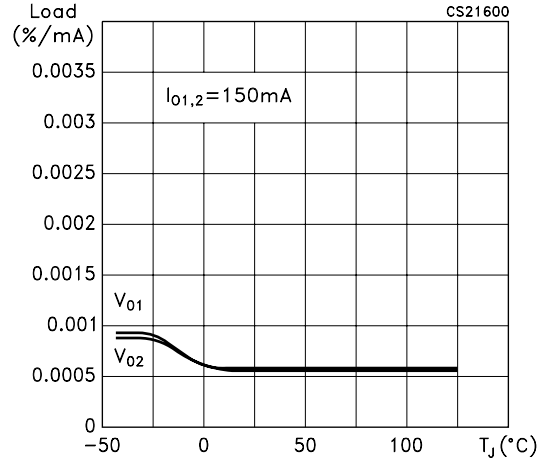


Figure 10: Quiescent Current vs Temperature

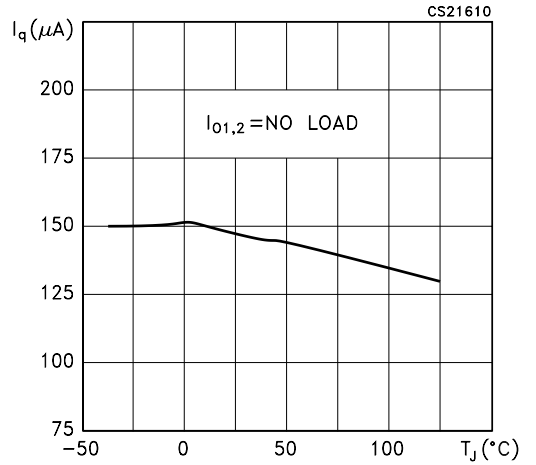


Figure 11: Quiescent Current vs Temperature

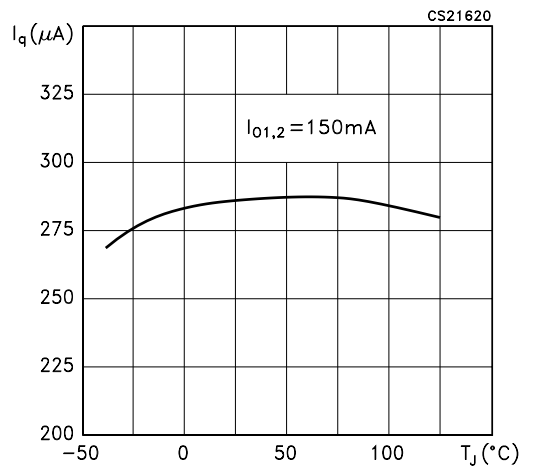


Figure 12: Supply Voltage Rejection vs Frequency

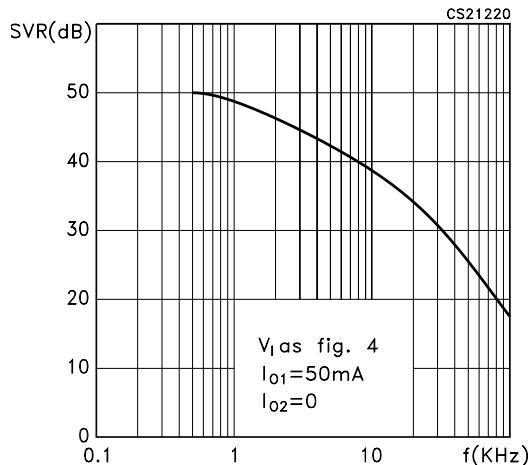


Figure 13: Supply Voltage Rejection vs Temperature

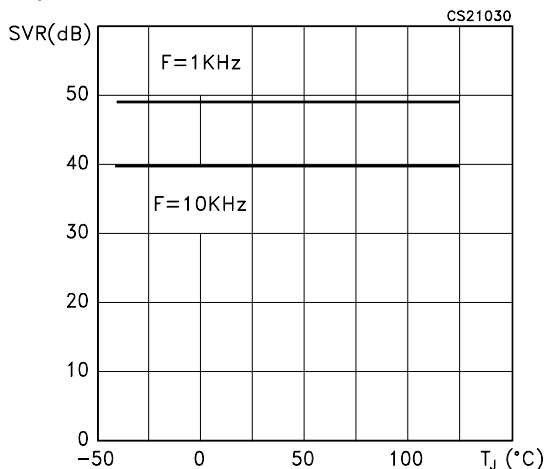
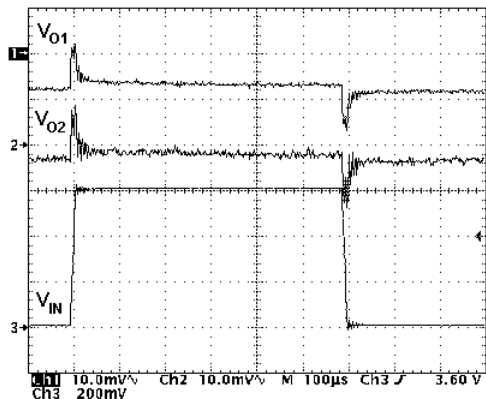
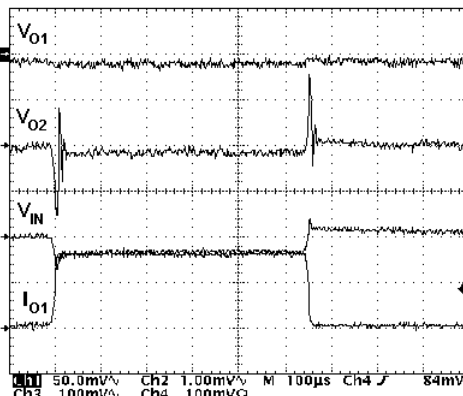


Figure 14: Line Transient Response



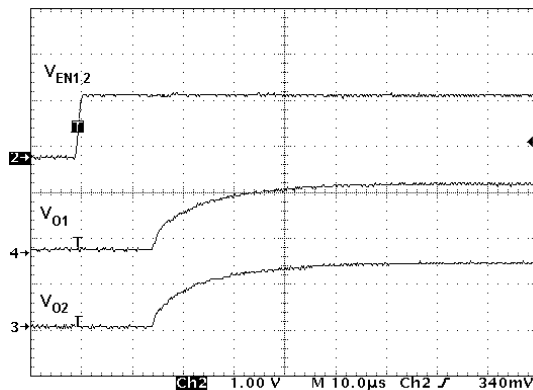
$V_1 = 3.2V$ to $3.8V$, $I_{O1} = I_{O2} = 150mA$, $T_R = T_F = 10µs$

Figure 15: Load Transient Response



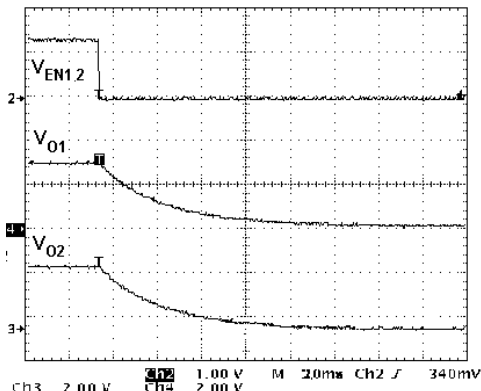
$I_{O1} = 1 mA$, $I_{O2} = 0mA$, $T_R = T_F = 10µs$

Figure 16: TURN-ON



$V_1 = 3.2V$, $V_{EN1,2} = 0$ to $1.4V$, $I_{O1,2} = 1mA$, $T_R = T_F = 1µs$

Figure 17: TURN-OFF



$V_1 = 3.2V$, $V_{EN1,2} = 1.4$ to $0V$, $I_{O1,2} = 1mA$, $T_R = T_F = 1µs$

APPLICATION INFORMATION**CURRENT LIMIT**

The device includes short-circuit protection. It includes a current limiter that controls the pass transistor's gate voltage to limit the output current to about 600mA.

THERMAL OVERLOAD PROTECTION

The Thermal over load protection limits total power dissipation in the device. When the junction temperature (T_J) exceeds +160°C, the thermal sensor sends a signal to the shutdown logic, turning off the pass transistors and allowing the device to cool. The pass transistors turns on again after the device's junction temperature typically cools by 20°C, resulting in a pulsed output during continuous thermal overload conditions.

POWER DISSIPATION

Maximum power dissipation of the device depends on the thermal resistance of the case and circuit board, the temperature difference between the die junction and ambient air, and the rate of air flow. The power dissipated by the device is:

$$P_D = I_O (V_I - V_O)$$

The maximum power dissipation is:

$$P_{MAX} = (T_{JMAX} - T_A) / R_{TH}$$

Where:

$$T_{JMAX} = +125^\circ\text{C}$$

T_A is the ambient temperature

R_{TH} thermal resistance.

The device's pins perform the dual function of providing an electrical connection as well as channeling heat away from the die. Use wide circuit-board traces and large, solid copper polygons to improve power dissipation. Using multiple vias to buried ground planes further enhances thermal conductivity.

INPUT CAPACITOR

An input capacitance of $\approx 1\mu\text{F}$ is required between the LD3986 input pin and ground (the amount of the capacitance may be increased without limit).

This capacitor must be located a distance of not more than 1cm from the input pin and returned to a clean analog ground. Any good quality ceramic, tantalum, or film capacitor may be used at the input.

Important: Tantalum capacitors can suffer catastrophic failures due to surge current when connected to a low impedance source of power (like a battery or a very large capacitor). If a tantalum capacitor is used at the input, it must be guaranteed by the manufacturer to have a surge current rating sufficient for the application.

There are no requirements for the ESR on the input capacitor, but tolerance and temperature coefficient must be considered when selecting the capacitor to ensure

the capacitance will be $\approx 1\mu\text{F}$ over the entire operating temperature range.

OUTPUT CAPACITOR

The LD3986 is designed specifically to work with very small ceramic output capacitors, any ceramic capacitor (temperature characteristics X7R, X5R, Z5U or Y5V) in 1 to 22 μF range with 5m. to 500m. ESR range is suitable in the LD3986 application circuit. It may also be possible to use tantalum or film capacitors at the output, but these are not as attractive for reasons of size and cost.

The output capacitor must meet the requirement for minimum amount of capacitance and also have an ESR (Equivalent Series Resistance) value which is within a stable range.

NOISE BYPASS CAPACITOR

Connecting a 0.01 μF capacitor between the C_{BYP} pin and ground significantly reduces noise on both regulator outputs.

This cap is connected directly to a high impedance node in the band gap reference circuit. Any significant loading on this node will cause a change on the regulated output voltage.

For this reason, DC leakage current through this pin must be kept as low as possible for best output voltage accuracy. The use of this 0.01 μF bypass capacitor is strongly recommended to prevent overshoot on the output during start up.

The types of capacitors best suited for the noise bypass capacitor are ceramic and film. High-quality ceramic capacitors with either NPO or COG dielectric typically have very low leakage. Polypropylene and polycarbonate film capacitors are available in small surface-mount packages and typically have extremely low leakage current. Unlike many other LDO's, addition of a noise reduction capacitor does not effect the transient response of the device.

TURN-ON/OFF INPUT OPERATION

Each LD3986 output is turned off by pulling the relevant EN pin low, and turned on by pulling it high. To assure proper operation, the signal

source used to drive the EN input must be able to swing above and below the specified turn-on/off voltage thresholds listed in the Electrical Characteristics section under Enable Input Logic Low and Enable Input Logic High.

Proper operation of the Enable function is guaranteed by driving EN pins with T_R and $T_F = 10$ ms.

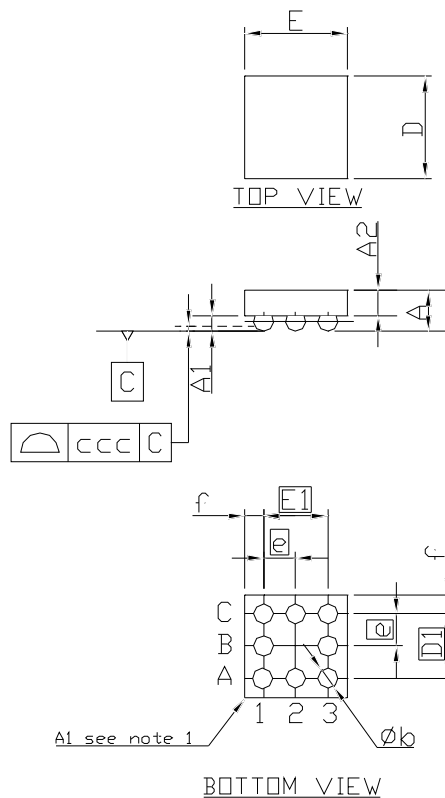
FAST ON-TIME

The LD3986 outputs are turned on after V_{REF} voltage reaches its final value (1.23V nominal). To speed up this process, the noise reduction capacitor at the bypass pin is charged with an

internal 70 μ A current source. The current source is turned off when the bandgap voltage reaches approximately 95% of its final value. The turn on time is determined by the time constant of the bypass capacitor. The smaller the capacitor value, the shorter the turn on time, but less noise gets reduced. As a result, turn on time and noise reduction need to be taken into design consideration when choosing the value of the bypass capacitor.

Flip-Chip8 MECHANICAL DATA

DIM.	mm.			mils		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
A	0.585	0.65	0.715	23.0	25.6	28.1
A1	0.21	0.25	0.29	8.3	9.8	11.4
A2		0.40			15.7	
b	0.265	0.315	0.365	10.4	12.4	14.4
D	1.52	1.57	1.62	59.8	61.8	63.8
D1		1			39.4	
E	1.52	1.57	1.62	59.8	61.8	63.8
E1		1			39.4	
e	0.45	0.5	0.55	17.7	19.7	20.7
f		0.285			11.2	
ccc		0.080			3.1	



7224720E

Table 6: Revision History

Date	Revision	Description of Changes
07-Dec-2004	1	First Release.
06-Jun-2005	2	Add New Part Number - Table 1.
22-Sep-2005	3	Order Codes has been updated.

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